

CORRECTION

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Correction: High-performance UV detectors based on room-temperature deposited amorphous Ga₂O₃ thin films by RF magnetron sputtering

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Correction for 'High-performance UV detectors based on room-temperature deposited amorphous Ga₂O₃ thin films by RF magnetron sputtering' by Shun Han *et al.*, *J. Mater. Chem. C*, 2019, **7**, 11834–11844.

The authors apologise for the incorrect corresponding email address for Deliang Zhu. The correct affiliation and contact information is as above.

The Royal Society of Chemistry apologises for these errors and any consequent inconvenience to authors and readers.

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